AN_11659 JN5169/001 RF System Tests Report Rev. 2.0 — 2015 March 15

Application note

Document information

Info	Content	
Keywords	Zigbee, JN5169, SMA, system	
Abstract	N5169 RF tests	



Revision history

Rev	Date	Description	
1.0	2014/03/12	Creation	
2.0	2015/03/15	JN5169 ES2 official samples update	

Contact information

For more information, please visit: http://www.nxp.com

1. Introduction

This paper provides the RF evaluation test results of the DR1185_JN5169 SMA module.

The version of the module is DR1185_1V1_version C

On this module the RF port of the JN5169 is connected to a SMA connector.

The module is plugged to a mother board called "Carrier Board" (DR1174_1V4)

All the measurements have been done in conducted mode.

Module under test: n° 50



Fig 1. DR1185 module and DR1174 carrier board (mother board)

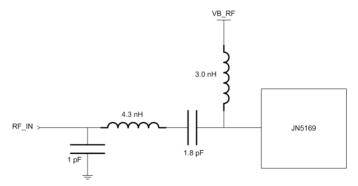


Fig 2. DR1185 front-end matching network

All the tests have been done with the test boards being supplied by the USB port.

1.1 List of Tests

Test standards	Results
ETSI EN 300 328 V1.8.1	PASS
IEEE 802.15.4 2011	PASS

A- Conducted tests

- a. Tx tests
 - i. Frequency accuracy
 - ii. Phase noise
 - iii. Tx power
 - iv. TX harmonics
 - v. 32MHz spurious
 - vi. Other TX spurious
 - vii. EVM & Offset EVM

b. Rx tests

- i. Sensitivity
- ii. Rx spurious
- iii. LO leakage
- iv. Interference rejection
- v. 3G immunity
- vi. LTE immunity

B- Return loss

a. Tx

b. Rx

1.2 SW

Prior to the measurements a binary code must be loaded into the Flash memory of the board.

The user Guide JN-UG-3099 describes how to use the Flash Programmer application for loading the code.

The binary code that has been used for the following tests is the CMET (Customer Module Evaluation Tool) version 4.00 compiled on 2015 March 5th.

The TERATERM terminal emulator is used to communicate with the chip.

2. Tests Summary

	EUROPE		<u> </u>	
	reference	Section	limit	Status
TX Maximum Power	ETSI EN 300 328	4.3.2.1	20 dBm	PASS
TX Spurious 30 MHz - 1GHz	ETSI EN 300 328	4.3.2.8.2	-36 or -54 dBm (depends on frequency) (100 kHz BW)	PASS
TX Spurious 1GHz - 12.5 GHz	ETSI EN 300 328	4.3.2.8.2	-30 dBm (1MHz BW)	PASS
EVM	802.15.4	10.3.8	35%	PASS
TX Frequency Tolerance	802.15.4	10.3.9	+/- 40 ppm	PASS
min of max power	802.15.4	10.3.10	-3 dBm	PASS
Phase noise (unspread)	No reference			For information

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Miscellaneous

	EUROPE			
	reference	Section	limit	Status
RX spurious 30 MHz - 1GHz	ETSI EN 300 328	4.3.2.9.2	-57 dBm (100 KHz)	PASS
RX spurious 1GHz - 12.5 GHz	ETSI EN 300 328	4.3.2.9.2	-47 dBm (1 MHz)	PASS
RX Sensitivity	802.15.4	10.3.4	-85 dBm	PASS
Interference rejection N+/-1 (adjacent)	802.15.4	10.3.5	0 dB	PASS
Interference rejection N+/-2 (alternate)	802.15.4	10.3.5	30 dB	PASS
RX Max input	802.15.4_2011	10.3.11	-20 dBm	Not tested
	Return loss in Tx m	ode		For information
Return loss (S11)				

Return loss in Rx mode

For information

3. Conducted Tests

3.1 TX tests

The TX power of the JN5169 can be adjusted by 3 ways:

- Coarse adjustments are achieved with the PAPx modes (6 modes from PAP0 to PAP5)
- 3 fine tuning steps allow to increase the TX Default power by 0.8 dB, 1.2 dB or 1.6 dB by adding 0.4, 0.8 or 1.2 mA extra biasing current in the TX block of the chip.
- A switchable attenuator allows to attenuate the power by 2.5 dB

All these TX power modes can be combined in order to give a high flexibility on the TX power.

In this document we will make reference only to four TX power configurations:

- > "TX default power": PAP5 + default biasing current + attenuator OFF
- > "TX default power + 0.8 dB": PAP5 + 0.4 mA extra biasing current + attenuator OFF
- > "TX default power + 1.2 dB": PAP5 + 0.8 mA extra biasing current + attenuator OFF
- > "TX default power + 1.6 dB": PAP5 + 1.2 mA extra biasing current + attenuator OFF

3.1.1 TX Test Set-Up

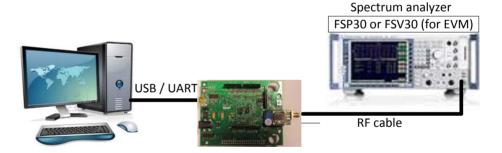


Fig 3. Conducted Tx test set up

3.1.2 Frequency Accuracy

Test method:

- Set the radio in :
 - o TX mode, CW, continuous mode, frequency: channel 18
- · Set analyzer to:
 - Center frequency = 2.44 GHz , span = 1 MHz , Ref amp = 20 dBm, RBW
 = 10 kHz
- Measure the CW frequency with the marker of the spectrum analyzer

Result:

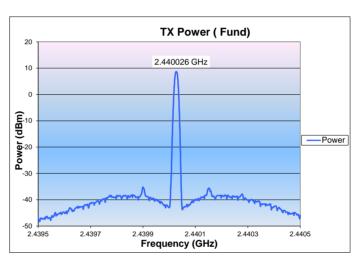


Fig 4. Frequency accuracy

- Measured frequency: 2.440026 GHz
- ppm value = (2440026 2440000) / 2.440 = + 10.7 ppm

Result	Target	802.15.4 limit
+ 10.7 ppm	+/- 25 ppm	+/- 40 ppm

Note: the frequency accuracy depends on the XTAL model. The model used on the DR1185 is **AELX32M00000S039A**.

3.1.3 Phase Noise

Test method:

- Set the radio in:
 - o TX mode, CW, continuous mode, frequency: channel 18
- · Set analyzer to:
 - o Center frequency = 2.44 GHz, span = 1 MHz, Ref amp = 20 dBm
- Measure the phase noise at 100 kHz offset frequency
 - o RBW (spectrum analyzer) = 10KHz (40dBc)

3.1.3.1 "TX Default Power" mode

Result:

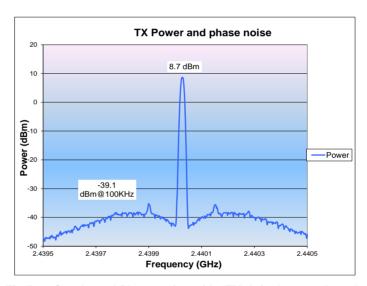


Fig 5. Conducted Phase noise with "TX default power" mode

- Marker value = -39.1dBm/10kHz →
 - o Marker delta = 8.7 (- 39.1) = 47.8 dB
 - o Phase noise = -47.8 -10 Log (10kHz) = -87.8 dBc/Hz

Note:

- Phase noise is only for information.
- There is no issue on this parameter.

3.1.3.2 "TX Default power + 1.6 dB" mode

Result:

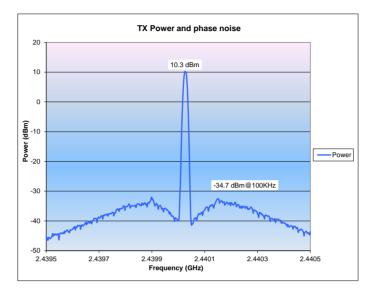


Fig 6. Conducted Phase noise with "TX default power + 1.6 dB" mode

- Marker value = -34.7 dBm/10kHz →
 - o Marker delta = 10.3 (- 34.7) = 45 dB
 - o Phase noise = 45 -10 Log (10kHz) = -85 dBc/Hz

Note:

- Phase noise is only for information.
- There is no issue on this parameter.

3.1.4 TX Power (fundamental)

Test method:

- · Set the radio in :
 - o TX mode, modulated, continuous mode
- · Set analyzer to:
 - Start freq = 2.4 GHz , Stop freq = 2.5 GHz , Ref amp = 20 dBm , sweep time = 100 ms , RBW = 3 MHz
 - o Max Hold mode
- Sweep all the channels from ch11 to ch26

3.1.4.1 "TX default Power" mode Result:

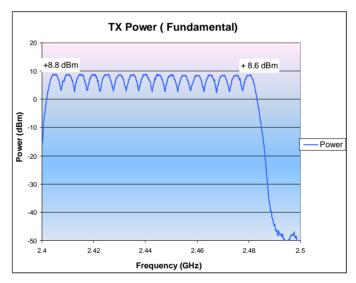


Fig 7. TX max power with "TX default power" mode

Maximum power is on channel 11: + 8.8 dBm

Minimum power is on channel 26:+ 8.6 dBm

Tilt over frequencies is: 0.2 dB

3.1.4.2 "TX Default power + 0.8 dB" mode Result:

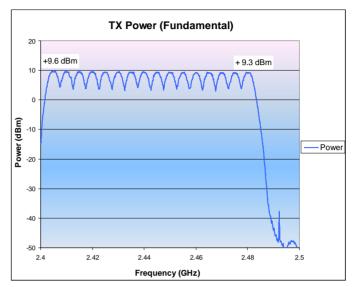


Fig 8. TX max power with "TX default power + 0.8 dB" mode

Maximum power is on channel 11: + 9.6 dBm

Minimum power is on channel 26:+ 9.3 dBm

Tilt over frequencies is: 0.3 dB

3.1.4.3 "TX Default power +1.2 dB" mode Result:

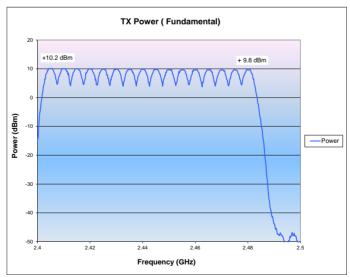


Fig 9. TX max power with "TX default power + 1.2 dB" mode

Maximum power is on channel 11: + 10.2 dBm

Minimum power is on channel 26:+ 9.8 dBm

Tilt over frequencies is: 0.4 dB

3.1.4.4 "TX Default power + 1.6 dB" mode Result:

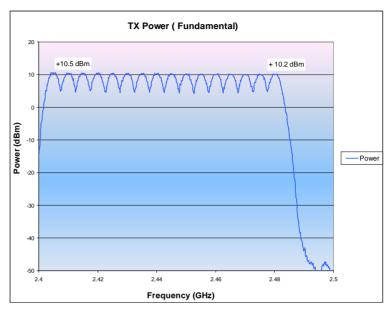


Fig 10. TX max power with "TX default power + 1.6 dB" mode

Maximum power is on channel 11: **10.5 dBm** Minimum power is on channel 26: **10.2 dBm**

Tilt over frequencies is: 0.3 dB

3.1.5 TX spurious

3.1.5.1 Global view from 0.3GHz to 12.5 GHz

Frequency: channel 18

a. With "TX Default Power" mode

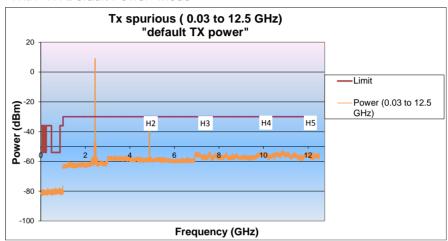


Fig 11. Conducted Tx spurious with "TX default power" mode



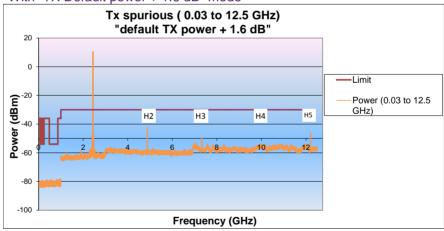


Fig 12. Conducted Tx spurious with "TX default power + 1.6 dB" mode

Conclusion:

- There are no TX spurs above the EN 300 328 limit
- The harmonics of the wanted signal can be detected with good margin to the limit. See detailed measurements in the following paragraphs.
- The spurs at +/- 32 MHz offset cannot be seen on this graph. They
 are below the limit with good margin. See detailed measurements
 in the following paragraphs.

3.1.5.2 H2

Test method:

- · Set the radio in:
 - o TX mode, modulated, continuous mode
- · Set analyzer to:
 - Start frequency = 4.8 GHz , Stop frequency = 5 GHz ,
 Ref amp = -20 dBm , sweep time = 100 ms , RBW = 1 MHz
 - o Max Hold mode
- Sweep all the channels from ch11 to ch26

a) With "TX Default Power" mode

Result:

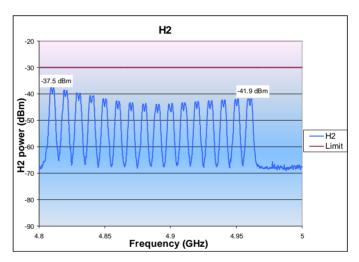


Fig 13. Conducted H2 spurious with "TX default power" mode

Maximum power is on channel 11: -37.5 dBm

Power at channel 26: -41.9 dBm

Conclusion: Good margin (7.5 dB)

b) With "TX Default Power + 1.6 dB" mode Result:

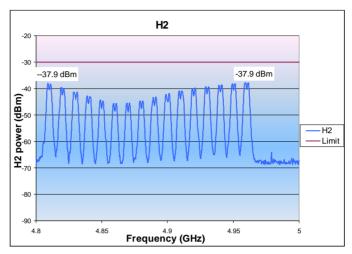


Fig 14. Conducted H2 spurious with "TX default power + 1.6 dB" mode

Maximum power is on channels 11 & 26: -37.9 dBm

Conclusion: Good margin (7.9 dB)

16 of 31

3.1.5.3 H3

Same method as H2 except the spectrum analyzer frequency start/stop are set to 7.2 and 7.5 GHz.

a) With "TX Default Power" mode Result:

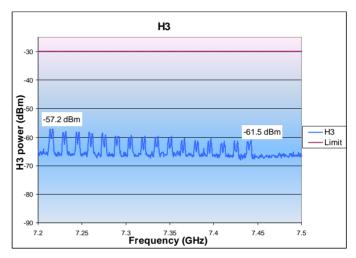


Fig 15. Conducted H3 spurious with "TX default power" mode

Maximum power is on channel 11: - 57.2 dBm

Power on channel 26: - 61.5 dBm

Conclusion: Good margin (27.2 dB)

b) With TX Default Power + 1.6 dB Result:

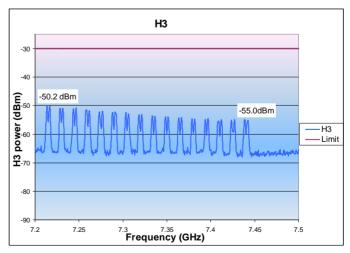


Fig 16. Conducted H3 spurious with "TX default power + 1.6 dB" mode

Maximum power is on channel 11: - 50.2 dBm

Power on channel 26: - 55.0 dBm

Conclusion: Good margin (20.2dB)

3.1.5.4 H4

Same method as H2 except the spectrum analyzer frequency span is set from 9.6 to 10.0 GHz.

a) With "TX Default Power" mode

Result

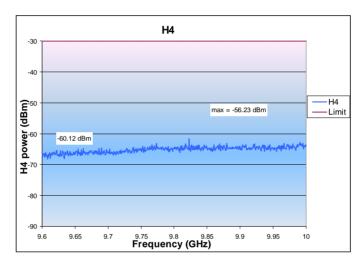


Fig 17. Conducted H4 spurious with "TX default power" mode

Conclusion: H4 harmonics cannot be detected.

b) With "TX Default Power + 1.6 dB" mode

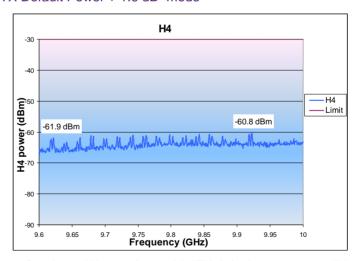


Fig 18. Conducted H4 spurious with "TX default power + 1.6 dB" mode

Power on channel 11: - 61.9 dBm

Maximum power is on channel 26: - 60.8 dBm

Conclusion: Good margin (30.8dB)

3.1.5.5 H5

Same method as H2 except the spectrum analyzer frequency span is set from 12 GHz to 12.5 GHz

Result:

The fifth harmonics are below the noise floor of the spectrum analyzer.

3.1.6 32 MHz spurious

Test method:

- Set the radio in TX, modulated, continuous mode
 - o TX mode, CW, continuous mode, frequency: channel 18
- Set analyzer to:
 - o Center frequency = 2.44 GHz, span = 100 MHz, Ref amp = 20 dBm
- Measure the spurs level at +/- 32 MHz frequency offset from the carrier frequency with the marker.

3.1.6.1 With "TX default power" mode

Result:

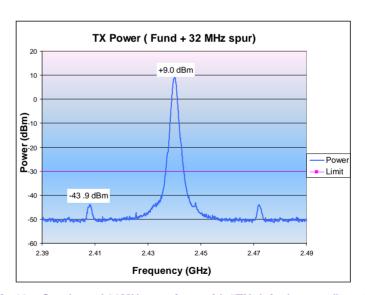


Fig 19. Conducted 32MHz spurious with "TX default power" mode

Fundamental peak level: 9.0 dBm

Left quartz (32MHz) spur peak level: -43.9 dBm Right quartz (32MHz) spur peak level: -44.1 dBm

Conclusion: Good margin: 13.9 dB

3.1.6.2 With "TX default power + 1.6 dB" mode

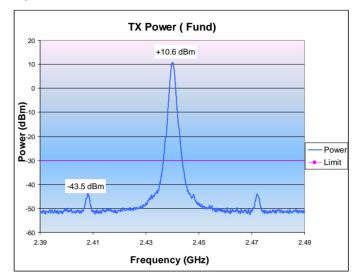


Fig 20. Conducted 32MHz spurious with "TX default power + 1.6 dB" mode

Fundamental peak level: 10.6 dBm

Left quartz (32MHz) spur peak level: -43.5 dBm Right quartz (32MHz) spur peak level: -44.0 dBm

Conclusion: Good margin: 13.5 dB

3.1.7 TX Modulation quality

3.1.7.1 Overview

Test conditions:

- Channel 18
- TX default power

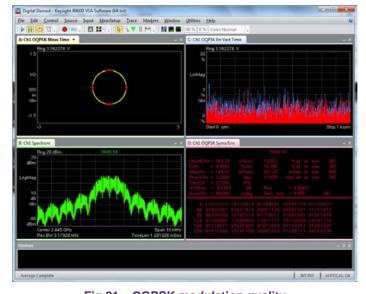


Fig 21. OQPSK modulation quality

3.1.7.2 EVM

Test method:

- Connect the RF port of the module to the R&S FSV30 Spectrum Analyzer. Use the specific menu of the Spectrum Analyzer to do the EVM measurement
- Set the JN5169 in "Tx default power" mode
- Set the TX frequency to channel 11
- Measure the EVM value.
- · Repeat the test for each channel

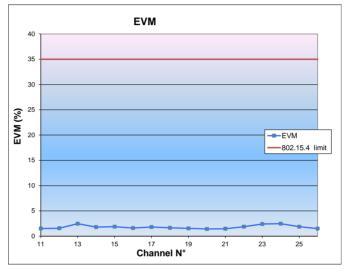


Fig 22. EVM

3.1.7.3 Offset EVM

<u>Test method</u>: same as EVM measurement. The same menu is used for EVM and Offset EVM measurements.

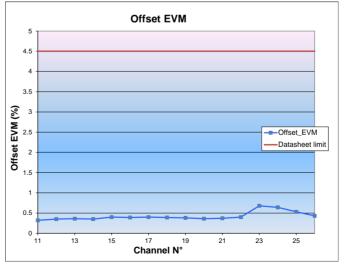


Fig 23. Offset EVM

Conclusion: both the EVM and Offset EVM are stable over frequency

3.2 RX tests

3.2.1 Test Set-Up

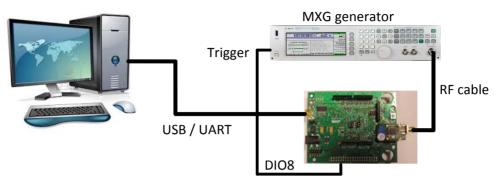


Fig 24. Conducted Rx test set up for sensitivity and receiver maximum input level

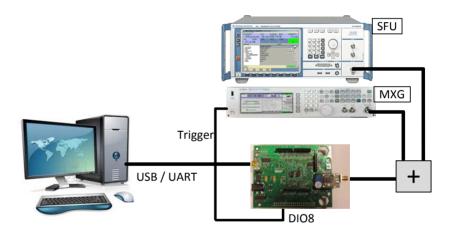


Fig 25. Conducted Rx test set up for interference rejection

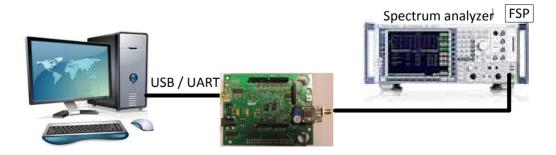


Fig 26. Conducted Rx test set up for spurious

3.2.2 Sensitivity

Test method:

The sensitivity tests were done in a Faraday cage.

Generator: Agilent NX5181 (MXG)

The generator is used in ARB mode to generate a pattern of 1000 packets of 20 octets. The DIO8 of the JN5169 is connected to the trigger input of the generator.

A TERATERM window is used to control the module.

- Set the receiver frequency to channel 11
- Set the module in "Trigger packet test".
- The connection is automatically established and the PER (Packet Error Rate) is measured.
- Decrease the level of the generator at the RF input of the module until PER = 1%.
- Repeat the test for each channel.

Result:

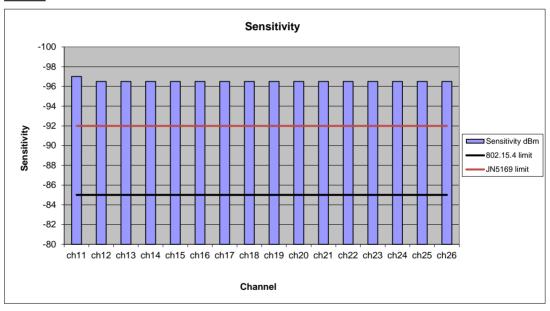


Fig 27. Sensitivity

Average value = -96.5 dBm.

3.2.3 Receiver maximum input level

Test method:

- The same test set-up as the sensitivity test is used.
- The "Trigger packet test" is used in the same way as the sensitivity test
- The measurement is done on channel 17 only.
- The signal level is increased up to the PER = 1%

Result:

The maximum power that can be delivered by the MXG generator is + 17 dBm. With this input level the PER = 0.

Conclusion:

The receiver maximum input level is higher than 17 dBm.

3.2.4 RX spurious

3.2.4.1 Wide Band

Test method:

- Set the radio in :
 - o Receiver mode, frequency: channel 18
- Set the analyzer to:
 - o Ref amp = 20 dBm, Trace = max hold, detector = max peak
 - Start/Stop frequency: 30 MHz / 1GHz
 - √ RBW = 100 kHz ,
 - Then Start/Stop frequency: 1 GHz/12.75 MHz
 - ✓ RBW = 1 MHz

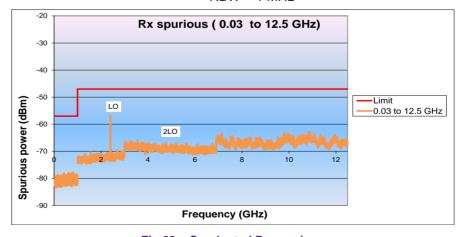


Fig 28. Conducted Rx spurious

<u>Note:</u> There are no spurs. Only LO leakage is detected. Detailed LO leakage measurement is described in the following paragraph.

3.2.4.2 LO leakage

Channel Frequency: 2405 MHz (channel 11)

LO frequency = channel frequency - 1.3125 MHz

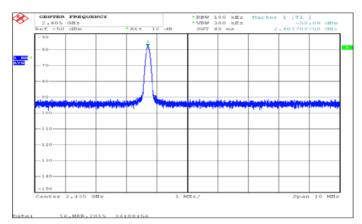


Fig 29. LO leakage

LO leakage = -58.1 dBm

3.2.5 Receiver Interference Rejection

3.2.5.1 Adjacent and alternate channels

Interferers are located in the adjacent channel (n-1 and n+1) or alternate channels (n-2 and n+2).

The test is performed for only one interfering signal at a time.

Test method:

Generator for desired signal: Agilent NX5181 (MXG)

Generator for interferers: R&S SFU

Criterion: PER < 1 %

The wanted signal is set to - 82 dBm. The interferer is increased until the PER threshold

has been reached.

Channels under test: 11, 18 and 26

Result:

		ch18		
		2405		
	n-2	n-2 n-1 n+1 n-		
	2395	2400	2410	2415
Interferer level (dBc)	39.2	18.2	33.2	42.7
802.15.4 limit (dB)	30	0	0	30
Margin (dB)	9.2	18.2	33.2	12.7

ch18				
2440				
n-2	n-1	n+1	n+2	
2430	2435	2445	2450	
39.2	18.2	33.2	42.2	
30	0	0	30	
9.2	18.2	33.2	12.2	

ch26				
2480				
n-2	n-1	n+1	n+2	
2470	2475	2485	2490	
38.2	18.2	32.7	42.2	
30	0	0	30	
8.2	18.2	32.7	12.2	

Fig 30. Adjacent and alternate rejection

Conclusion: 8.2 dB margin, worst case.

3.2.5.2 N-3 and n+3 channels

Test method:

Same as Adjacent and alternate channels but the interferer is set at 15 MHz offset from the desired channel.

Result:

	ch11 2405	
	n-3	n+3
	2390	2420
Interferer level (dBc)	44.2	47.7

ch18		
2440		
n-3 n+3		
2425	2455	
44.7 46.7		

 ch26

 2480

 n-3
 n+3

 2465
 2495

 44.7
 46.7

Fig 31. Other In Band rejection

Note: This test is for information. There are no specifications for it.

3.2.5.3 3G blocker

A CW is used as a 3 G interferer. It is set at 2100 MHz.

Test method:

Generator for desired signal: Agilent NX5181 (MXG)

Generator for 3G blocker: R&S SFU

Criterion: PER < 1 %

The wanted signal is set to - 82 dBm. The interferer level is increased until the PER $\,$

threshold has been reached.

Channels under test: 11.

Result:



Fig 32. 3G immunity

Note: This test is for information. There are no specifications for it.

3.2.5.4 LTE blocker (2500 MHz band)

A CW is used as a LTE interferer. It is set at 2500 MHz.

Test method:

Generator for desired signal: Agilent NX5181 (MXG)

Generator for LTE blocker: R&S SFU

Criterion: PER < 1 %

The wanted signal is set to - 82 dBm. The interferer level is increased until the PER

threshold has been reached.

Channels under test: 26.

Result:

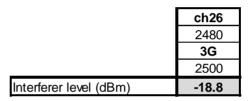


Fig 33. LTE immunity

Note: This test is for information. There are no specifications for it.

4. Return loss

4.1 TX

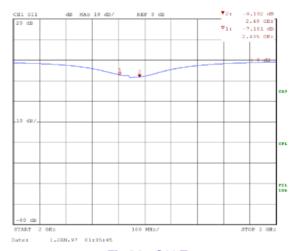


Fig 34. S11 Tx -8.2 dB (2.48 GHz) <S11< -7.2 dB (2.405GHz)

4.2 RX

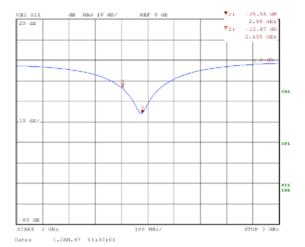


Fig 35. S11 Rx

-25.5.6dB (2.48 GHz) <S11< -12.7 dB (2.405 GHz)

Note: These tests are for information. There are no specifications for them.

5. Conclusion

Beyond the R&TTE and 812.15.4 compliances, these radio tests prove the good performances of the JN5169 wireless Zigbee microcontroller.

6. References

ETS EN 300 328: European Telecommunication Standard - Radio Equipment and Systems (RES) Wideband data transmission systems, Technical characteristics and test conditions for data transmission equipment operating in the 2.4GHz ISM band and using spread spectrum modulation techniques

IEEE 802.15.4: IEEE standard for Information technology – Telecommunications and information exchange between systems – Local and metropolitan area networks – Specific requirements – Part 15.4: Wireless Medium Access Control (MAC) and Physical Layer (PHY) Specifications for Low Rate Wireless Personnel Area Networks (LR-WPANs)

7. Legal information

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8. List of figures

Fig 1.	DR1185 module and DR1174 carrier board (mother board)		
Fig 2.	DR1185 front-end matching network	3	
Fig 3.	Conducted Tx test set up	7	
Fig 4.	Frequency accuracy	8	
Fig 5.	Conducted Phase noise with "TX default power" mode	9	
Fig 6.	Conducted Phase noise with "TX default power + 1.6 dB" mode	10	
Fig 7.	TX max power with "TX default power" mode	11	
Fig 8.	TX max power with "TX default power + 0.8 dB" mode	12	
Fig 9.	TX max power with "TX default power + 1.2 dB" mode	12	
Fig 10.	TX max power with "TX default power + 1.6 dB" mode	13	
Fig 11.	Conducted Tx spurious with "TX default power" mode	14	
Fig 12.	Conducted Tx spurious with "TX default power + 1.6 dB" mode	14	
Fig 13.	Conducted H2 spurious with "TX default power" mode	15	
Fig 14.	Conducted H2 spurious with "TX default power + 1.6 dB" mode	16	
Fig 15.	Conducted H3 spurious with "TX default power" mode	17	
Fig 16.	Conducted H3 spurious with "TX default power + 1.6 dB" mode	17	
Fig 17.	Conducted H4 spurious with "TX default power" mode	18	
Fig 18.	Conducted H4 spurious with "TX default power + 1.6 dB" mode	18	
Fig 19.	Conducted 32MHz spurious with "TX default power" mode	19	
Fig 20.	Conducted 32MHz spurious with "TX default power + 1.6 dB" mode	20	
Fig 21.	OQPSK modulation quality	20	
Fig 22.	EVM	21	
Fig 23.	Offset EVM	21	
Fig 24.	Conducted Rx test set up for sensitivity and receiver maximum input level	22	
Fig 25.	Conducted Rx test set up for interference rejection	22	
Fig 26.	Conducted Rx test set up for spurious	22	
Fig 27.	Sensitivity	23	
Fig 28.	Conducted Rx spurious	24	
Fig 29.	LO leakage	25	
Fig 30.	Adjacent and alternate rejection	25	
Fig 31.	Other In Band rejection	26	
Fig 32.	3G immunity	26	
Fig 33.	LTE immunity	27	
Fig 34.	S11 Tx	27	
Fia 35.	S11 Rx	28	

9. Contents

1.	Introduction3
1.1	List of Tests4
1.2	SW4
2.	Tests Summary5
3.	Conducted Tests7
3.1	TX tests7
3.1.1	TX Test Set-Up7
3.1.2	Frequency Accuracy8
3.1.3	Phase Noise9
3.1.3.1	"TX Default Power" mode9
3.1.3.2	"TX Default power + 1.6 dB" mode10
3.1.4	TX Power (fundamental)11
3.1.4.1	"TX default Power" mode11
3.1.4.2	"TX Default power + 0.8 dB" mode12
3.1.4.3	"TX Default power +1.2 dB" mode12
3.1.4.4	"TX Default power + 1.6 dB" mode13
3.1.5	TX spurious14
3.1.5.1	Global view from 0.3GHz to 12.5 GHz14
3.1.5.2	H215
3.1.5.3	H317
3.1.5.4	H418
3.1.5.5	H5^19
3.1.6	32 MHz spurious
3.1.6.1	With "TX default power" mode
3.1.6.2	With "TX default power + 1.6 dB" moc \ 20
3.1.7	TX Modulation quality
3.1.7.1	Overview
3.1.7.2	
3.1.7.3	Offset EVM
3.2	RX tests22
3.2.1	RX tests
3.2.2	Sensitivity
3.2.3	Receiver maximu input levei24
3.2.4	RX spurious24
3.2.4.1	Wide Bar 24 LO leakage 25
3.2.4.2	LO leakagt25
3.2.5	Recinter rencr ejection25
3.2.5.1	Adj. ent 'alt. e channels25
3.2.5.2	N-3 and ri+3 c annels26
3.2.5.3	3G blockr26
3.2.5.4	LTE blocker (2500 MHz band)27
4.	Return loss27
4.1	TX27
4.2	RX28
5.	Conclusion28

6.	References	28
7.	Legal information	29
7.1	Definitions	
7.2	Disclaimers	29
7.3	Licenses	29
7.4	Patents	29
7.5	Trademarks	29
8.	List of figures	30
9.	Contents	31

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